Vishay Semiconductors

Ultrafast Rectifier, 2 x 15 A FRED Pt[®]



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _R	600 V				
V _F at I _F	0.9 V				
t _{rr}	55 ns				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Common cathode				

FEATURES

- • Ultrafast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- · For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RA	TINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V _{RRM}		600	V
Average rectified forward current	per device		T _{solder pad} = 143 °C	30	_
	per diode	IF(AV)		15	
Non-repetitive peak surge current per device	per device		$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	300	A
	per diode	IFSM		160	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-		
Forward voltage, per diade	V _F	I _F = 15 A	-	1.03	1.25	V	
Forward voltage, per diode		I _F = 15 A, T _J = 150 °C	-	0.9	1.1		
Reverse leakage current, per diode	I _R	$V_{R} = V_{R}$ rated	-	-	15	μA	
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	70	300		
Junction capacitance, per diode	CT	V _R = 600 V	-	13	-	pF	

RoHS COMPLIANT HALOGEN FREE

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I _F = 1 A, dI _F /dt = 50 A	/μs, V _R = 30 V	-	55	-	
Boyeroo recovery time	÷	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	65	
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 15 A, dI _F /dt = 500 A/μs, V _B = 400 V	-	96	-	- ns
		T _J = 125 °C		-	150	-	
Peak recovery current		T _J = 25 °C		-	18	-	А
Peak recovery current I _{RRM}	IRRM	T _J = 125 °C		-	26	-	~
	0	T _J = 25 °C		-	1.0	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	2.0	-	μC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, per diode junction to mount	R _{thJM}		-	1.2	1.7	°C/W
Approvimeto weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style SMPD (TO-263AC)		30CI	DU06	



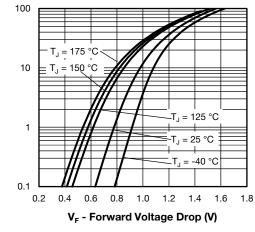


Fig. 1 - Typical Forward Voltage Drop Characteristics

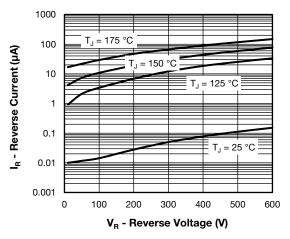


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-30CDU06HM3

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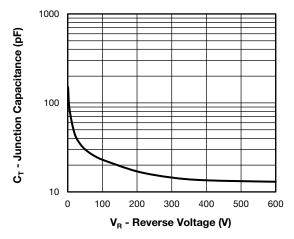


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

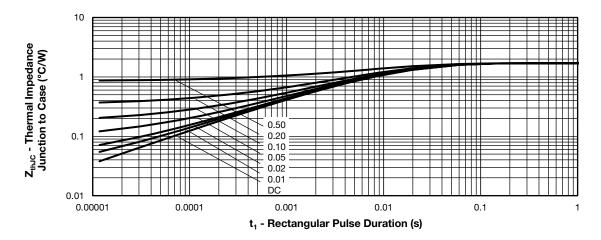
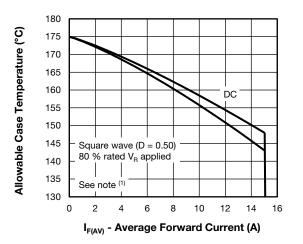
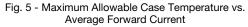


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

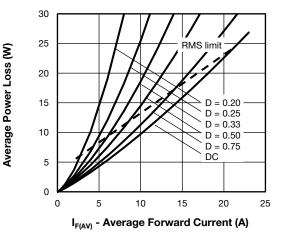


Fig. 6 - Forward Power Loss Characteristics

Revision: 29-Jan-2021

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Document Number: 95823

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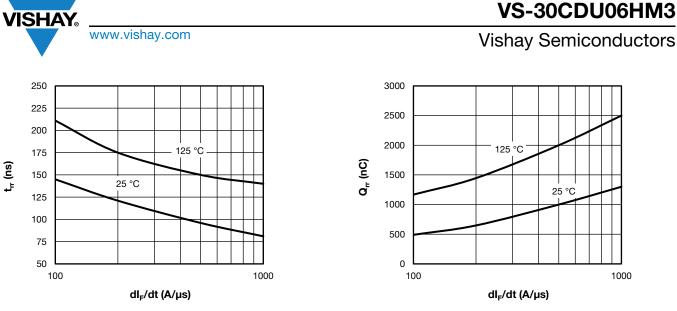


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

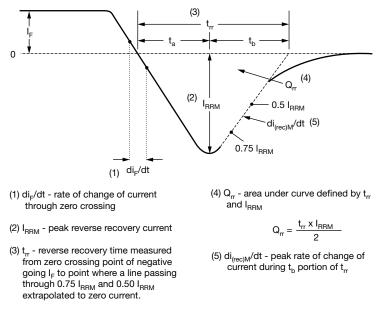


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

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SHAY

Device code	vs-	30	С	D	U	06	н	М3
	1	2	3	4	5	6	7	8
	2	- Cur	rent rati	nicondu ing (30 <i>F</i> figuratio	4)	oduct		
	H	- D =		package package				
	7	- Voli - H =	tage coo AEC-Q	st recove de (06 = 101 qua jen-free,	600 V) alified	complia	ant, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-30CDU06HM3/I	2000	2000	13" diameter plastic tape and reel				

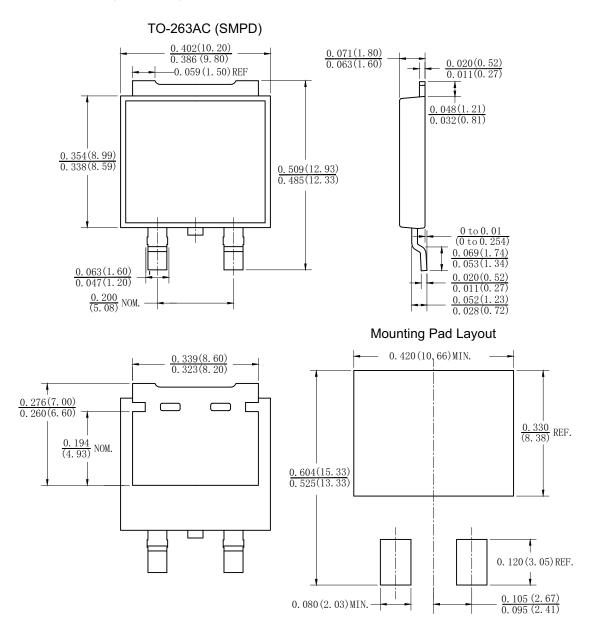
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96576				





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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